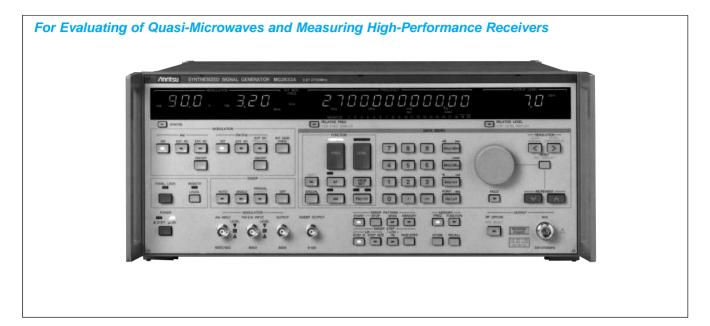
SYNTHESIZED SIGNAL GENERATOR

MG3633A

10 kHz to 2700 MHz





The MG3633A has excellent frequency resolution, frequency switching speed, signal purity, and a high output level, in addition to amplitude, frequency, and phase modulation functions. Also, sweep functions are provided for carrier frequency, output level, and modulation frequency so an appropriate sweep can be performed for various devices to be measured.

Also, the MG3633A has a frequency memory that can store 1000 carrier frequencies and a function memory that stores 100 panel settings. Moreover, since the maximum output level is +17 dBm, it can be used for various local signal sources.

The MG3633A is suitable for research and development of mobile communications in the quasi-microwave band, performance evaluation, characteristics testing, and adjustment of various types of radio equipment such as digital land-based mobile communications, mobile satellite communications, satellite broadcasting, and radio LANs.

Features

Low noise

By using both the latest synthesizer and RF-device technologies and optical data links in the internal control circuit, the SSB phase noise has been cut to –140 dBc/Hz (CW, 1.1 GHz, offset 20 kHz). In particular, the MG3633A shows its power in measurement of narrowband radio equipment S/N ratio and adjacent channel selectivity.

• High accuracy and high-output level

Low levels of -123 dBm can be set with ± 1 dB accuracy by using a high-accuracy programmable attenuator. The output level can be displayed in units of dBm, dB μ V, V, mV, and μ V or as a relative value (dB).

Modulation characteristics

The MG3633A has AM, FM, \wp M, and a combination of all three modulation functions. A DC mode is provided for FM, which makes simulation of digital transmissions for a pager possible. Also, a built-in AF oscillator with a 0.1 Hz to 100 kHz synthesizer can handle various modulations.

Quasi-microwave output

The MG3633A covers a wide range (from 10 kHz to 2700 MHz) and is suitable for research and development, as well as production of quasi-microwave band radio equipment.

Performance

Signal purity

The MG3633Å has excellent spectral purity. As shown in the Fig. 1, the SSB phase noise at 1 GHz with 20 kHz signal offset is –140 dBc/Hz. In particular, this shows its power for generating signals used for testing radio receiver selectivity, for generating high-speed clocks of A/D converters and dividers, as well as for generating standard signals for communications links. Also, since the residual FM is 0.8 Hz rms or less (1.28 GHz or less), even the S/N ratio of narrowband mobile radio equipment can be measured with sufficient margin (Fig. 2)

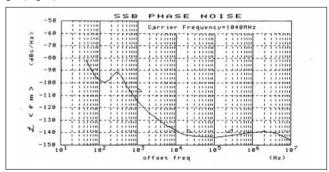


Fig. 1 SSB phase noise

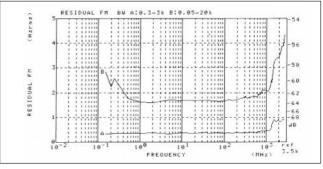


Fig. 2 Residual FM

• Output level characteristics

A maximum output of +17 dBm can be obtained over a wide frequency range so 2-signal or 3-signal testing can be done easily. A high-accuracy highly-reliable programmable attenuator (life cycle over 3 million times) is used and, since flat output characteristics are obtained by internal calibration over a wide range from 10 kHz to 2.7 GHz, it is effective for testing antennas and cables (Fig. 3).

Moreover, compensation data for obtaining flat levels at cable ends can be input by using a power meter, GPIB, controller, and frequency-response compensation software (option).

• Continuously variable output level

The MG3633A can output continuously-variable signals in a 20 dB range with 0.1 dB steps at any level. This is especially convenient for measuring the dynamic range of magnetic tape and squelch sensitivity of radios which produce hysteresis phenomenon as a result of level variation.

AM

A high-accuracy AM wave is generated over a wide frequency range (Fig. 4). Countermeasures against carrier-wave variation due to vibration permit even SSB radio equipment to be tested with confidence.

FM

FM with a maximum frequency deviation of 3.2 MHz is possible (1.28 to 2.7 GHz). Also if the frequency deviation is too low, automatic operation is carried out in the stabilized DC-FM mode so even digital data transmission equipment such as papers can be tested (Fig. 5).

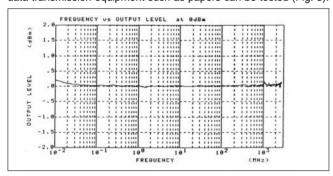


Fig. 3 Output level frequency response

AH FREQ RESPONSE at 1358HHz 7dBm 5 4 7 8 9 10 11 10 11 10 11 10 11 10 11 10 11 10 11 10 11 10 11 1

Fig. 4 AM modulation frequency characteristics

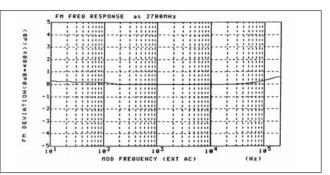


Fig. 5 FM modulation frequency characteristics

Specifications

Carrier frequency	Range	10 kHz to 2700 MHz							
	Resolution	0.01 Hz							
	Accuracy	Same as that of the reference oscillator							
	Internal reference oscillator*1	Frequency: 10 MHz Start-up characteristics: After 30 minutes of operation: $\le 1 \times 10^{-7}$ /day, after 60 minutes of operation: $\le 5 \times 10^{-8}$ /day, Aging rate: After 24 hours of operation: $\le 2 \times 10^{-8}$ /day, Temperature characteristics: $\pm 5 \times 10^{-8}$ (0° to 50°C)							
	External reference signal input	10 MHz, TTL Level, BNC connector on rear panel							
	Reference signal output	10 MHz, TTL Level, BNC connector on rear panel							
	Switching time	≤10 ms (time from last command until frequency has stabilized to within ±500 Hz of set frequency, during remote operation)							
	Range	-143 to +23 dBm							
	Units	dBm, dBμV, V, mV, μV (Terminated and open voltages are selectable for dBμV, V, mV or μV.)							
	Resolution	0.1 dB							
	Frequency response	±0.5 dB referred to 0 dBm (<1280 MHz), ±1 dB referred to 0 dBm (≥1280 MHz)							
	Accuracy	Output level	10 kHz to <1280 MHz	≥1280 MHz					
		+17.1 to +23 dBm	-	_					
		+15.1 to +17 dBm	±1 dB	_					
Output		-122.9 to +15 dBm	±1 dB	±2 dB					
		-132.9 to -123 dBm	±3 dB	±4 dB					
		-143 to -133 dBm	-	_					
	Impedance	50 Ω, N-type connector VSWR: ≤1.5 (<1280 MHz, ≤–3 dBm), ≤1.8 (≥1280 MHz, ≤–3 dBm)							
	Switching time	Time from last command until output level is stabilized, during remote operation:≤25 ms (at LEVEL NORMAL mode) ≤80 ms (when setting level is crossing over −59 dBm, at LEVEL NORMAL mode) ≤5 ms (at LEVEL CONTINUOUS mode)							
	Interference radiation	≤1 μV (Value is voltage terminated with 50 Ω load, measured 25 mm from front panel with a two-turn 25 mm diameter loop antenna.) Except sweep mode							

		At +7 dBm, CW mode: (fc: carrier fre	· · · · · · · · · · · · · · · · · · ·							
	Spurious	Harmonics (2nd, 3rd): ≤–30 dBc (at ≥100 kHz) Sub-harmonics (fc/2, 3fc/2, 5fc/2): None (at <1280 MHz), ≤–30 dBc (at ≥1280 MHz) Non-harmonics: ≤–80 dBc (fc<640 MHz, ≥10 kHz offset) ≤–74 dBc (640 MHz≤fc<1280 MHz, ≥10 kHz offset) ≤–68 dBc (fc≥1280 MHz, ≥10 kHz offset)								
		At +7 dBm, CW mode, 0°to 35°C								
		Offset frequency 1 kHz 20 to 300 kHz								
		0.01 to <40 MHz								
Signal purity		40 to <300 MHz	-119 dBc/Hz	-145	dBc/Hz					
	SSB phase noise	300 to <600 MHz	-143 dBc/Hz							
	,	600 to <1100 MHz	-140	dBc/Hz						
		1.1 to <2.4 GHz								
		2.4 to 2.7 GHz								
		Floor noise: ≤145 dBc/Hz (40 to <1100 MHz)								
	Residual AM	≤0.02% rms at ≥150 kHz (demodulat	ion band: 300 Hz to 3 kHz)							
	Residual FM	≤0.8 Hz rms at <1280 MHz (demodulation band: 300 Hz to 3 kHz) ≤4 Hz rms at <1280 MHz (demodulation band: 50 Hz to 20 kHz)								
	Range	0 to 100%								
	Resolution	0.1%								
	Internal modulation frequency	Fixed frequency: 400 Hz, 1 kHz Variable frequency: 0.1 Hz to 50 kHz, 0.1 Hz resolution Frequency accuracy: 100 ppm								
	Accuracy	± (5% of indicated value +2%) [at ≥2	250 kHz, ≤+7 dBm, 0 to 90% and interna	al 1 kHz]						
		At ≤+7 dBm, ±1 dB bandwidth								
	Frequency response	Lower modulation frequency limit	,							
Amplitude modulation		Upper modulation frequency limit	Modulation Carrier factor frequency	0 to 30%	30.1 to 80%					
modulation			0.25 MHz≤fc<0.5 MHz	5 kHz	5 kHz					
			0.5 MHz≤fc<80 MHz	20 kHz	10 kHz					
			80MHz≤fc	50 kHz	20 kHz					
	External modulation	Input level: Approx. 2 Vp-p ,600 Ω Input Impedance: Nominal 600 Ω								
	Depth	≤1% (at ≥1 MHz, ≤+7 dBm, internal 1 kHz, 30%) ≤3% (at ≥1 MHz, ≤+7 dBm, internal 1 kHz, 80%) ≤3% (at 250 kHz≤fc<1 MHz, ≤+7 dBm, internal 1 kHz, 30%) ≤10% (at 250 kHz≤fc<1 MHz, ≤+7 dBm, internal 1 kHz, 80%)								
	Incidental FM	≤200 Hz peak (at ≥250 kHz, ≤+7 dBm, 1 kHz, 30%, demodulation band 0.3 to 3 kHz)								
	Range	0 to 400 kHz (1 MHz≤fc<40 MHz) 0 to 800 kHz (320 MHz≤fc<640 MHz) 0 to 100 kHz (40 MHz≤fc<80 MHz) 0 to 1.6 MHz (640 MHz≤fc<1280 MHz) 0 to 200 kHz (80 MHz≤fc<160 MHz) 0 to 400 kHz (160 MHz≤fc<320 MHz) 0 to 3.2 MHz (1280 MHz≤fc)								
	Resolution	10 Hz (0 to 9.99 kHz deviation) 1 kHz (100 to 666 kHz deviation) 100 Hz (10 to 99.9 kHz deviation) 10 kHz (1 to 3.2 MHz deviation)								
_	Internal modulation frequency	Fixed frequency: 400 Hz, 1 kHz Variable frequency: 0.1 to 100 kHz. 0.1 Hz resolution Frequency accuracy: 100 ppm								
Frequency modulation	Accuracy	± (5% of indicated value +20 Hz) [internal 1 kHz]								
modulation	Modulation frequency response	±1 dB bandwidth Frequency range: 20 Hz to 100 kHz (EXT AC mode), DC to 100 kHz (EXT DC mode)								
	External modulation	Input level: Approx. 2 Vp-p/600 Ω Input impedance: Nominal 600 Ω								
	Distortion	≤1% (internal 1 kHz, 3.5 kHz deviation)								
	Incidental AM	≤0.4% (internal 1 kHz, 22.5 kHz deviation, demodulation band 0.3 to 3 kHz)								
	Carrier frequency accuracy in DC-FM mode	±500 Hz for 30-minute period after calibration and 2-hour warm-up (at <1280 MHz, <10 kHz deviation)								
Phase modulation	Range	0 to 80 rad (1 MHz≤fc<40 MHz) 0 to 160 rad (320 MHz≤fc<640 MHz) 0 to 20 rad (40 MHz≤fc<80 MHz) 0 to 320 rad (640 MHz≤fc<1280 MHz) 0 to 40 rad (80 MHz≤fc<160 MHz) 0 to 640 rad (1280 MHz≤fc) 0 to 80 rad (160 MHz≤fc<320 MHz) Besides radian, deg unit is also possible for phase deviation display. However, max. 999 deg.								
	Resolution	0.01 rad (0 to 9.99 rad deviation), 1 rad (100 to 640 rad deviation), 0.1 rad (10 to 99.9 rad deviation)								
	Internal modulation frequency	Fixed frequency: 400 Hz, 1 kHz Variable frequency: 0.1 Hz to 5 kHz, 0.1 Hz resolution Frequency accuracy: 100 ppm								
	Accuracy	±(10% of indicated value +0.05 rad)	[internal 1 kHz modulation]							
	Modulation frequency response	±1 dB bandwidth Frequency range: 20 Hz to 5 kHz (EXT AC mode), DC to 5 kHz (EXT DC mode)								

SIGNAL GENERATORS

Phase	External modulation	Input level: Approx. 2 Vp-p/600 Ω Input impedance: Nominal 600 Ω									
modulation	Distortion	≤1% (internal 1 kHz, 5 rad modulation)									
Internal modulation	Frequency range	400 Hz, 1 kHz (fixed oscillator) 0.1 Hz to 100 kHz (variable oscillator) DC voltage signals equivalent peak values of internal modulating sine wave can be applied as a modulating signal using the SPECIAL FUNCTION.									
signal	Resolution	0.1 Hz									
J	Frequency accuracy	100 ppm									
	Distortion	≤0.03% (fixe	d, 400	0 Hz and 1 kHz	:), ≤0.3%	6 (variab	ole, 20 Hz to 50) kHz)			
Memory	Frequency memory	1000 carrier	frequ	encies (store/re	ecall)						
function	Function memory	100 panel se	ettings	s (store recall)							
	Sweep mode	Carrier frequency, output level, AF frequency									
		Carrier frequency Output level AF frequency									
						Carrie	er frequency	Output leve	el AF	frequency	
		Pattern	-	art/stop			7	√*2		V	
			_	enter/span			√	•		√ 	
			Entering number of steps √ –			√ 					
		Step	Entering step size			√	√*3		√ /		
Swoon	Sweep pattern		LOG 1%			√			√		
Sweep function						Freque	ency memory	Function mem	ory		
			Con	tinuous address	3		√	√			
		Pattern	Random address			√	√				
			Con	Continuous, random mixed			√	√			
		Maximum number of steps				20*4	20*4				
	Sweep time	0.1 ms to 600 s, 0.01 ms resolution (minimum time depends on the switching time of each function.)									
	Marker	One movable marker									
	Sweep signal output	Staircase (saw-tooth waveform), Start point: 0 V, Stop point: 10 V									
	Modulation signal output	Modulation signal is output when modulating. Output level: Approx. 2 Vp-p/600 Ω									
		Simultaneous modulation is possible in combinations shown below.									
	Simultaneous modulation			INT AM	EXT	AM	INT FM	EXT FM	INT øM		
		EXT øM		√	1			_	√*6		
		INT øM		√*5	1			_	,		
		EXT FM		√ √	1		√*6				
Other		INT FM		√*5	1		•	J			
functions		EXT AM		√		'					
	Relative value display	Carrier frequ	iency	output level							
	Continuously variable output level mode	Carrier frequency, output level Continuously variable within a ±10 dB range of the set level									
	Trigger function	Step size: 0.1 dB Previously programmed operation procedure can be started by a trigger input through its input terminal (on rear panel, BNC connector, TTL level). Maximum program steps for triggered operation: 99 steps									
	Memory backup			stored when po					•		
	GPIB), DC1, DT1, C0)		
Reverse power		Maximum reverse input power: 50 W (<1000 MHz), 25 W (≥1000 MHz), ±DC 50 V									
Operating temperature		0° to 50°C									
Power		* ⁷ Vac ⁺¹⁰ ₋₁₅ %, 48 to 63 Hz, ≤270 VA									
Dimensions and mass		426 (W) x 177 (H) x 451 (D) mm, ≤32 kg									
EMC		EN61326: 1997/A1: 1998 (Class A) EN61000-3-2: 1995/A2: 1998 (Class A)									
LVD		EN61326: 1997/A1: 1998 (Annex A) EN61010-1: 1993/A2: 1995 (Installation Category II Pollution degree 2)									
LVD		EN61010-1: 1993/A2: 1995 (Installation Category II, Pollution degree 2)									

^{*1:} Aging rates up to 5 x 10⁻¹⁰/day are available as option. *2: Step width: Max. 20 dB *3: 0.1 dB step size only

^{*3. 0.1} da step size only

*4: One continuous address setting is counted as 3 steps.

*5: Same one internal modulation frequency is used.

*6: Different deviation settings are possible for INT and EXT modulations (using the SPECIAL FUNCTION).

*7: Specify one nominal line voltage between 100 and 240 V when ordering. However maximum operational voltage is limited to 250 V.

Options

Reference oscillators		Standard model	Option 01	Option 02	Option 03
Start-up After 30 minutes operation		1 x 10 ⁻⁷ /day	7 x 10 ⁻⁸ /day	_	_
characteristics After 60 minutes operation		5 x 10 ⁻⁸ /day	3 x 10 ⁻⁸ /day	2 x 10 ⁻⁸ /day	-
After 24 hours operation		2 x 10 ⁻⁸ /day	5 x 10 ⁻⁹ /day	2 x 10 ⁻⁹ /day	-
Aging rate After 48 hours operation		-	-	-	5 x 10 ⁻¹⁰ /day
Temperature characteristics (0° to 50°C)		±5 x 10 ⁻⁸	±5 x 10 ⁻⁸	±1.5 x 10 ⁻⁸	±5 x 10 ⁻⁹

Option 04: Rear RF output, SMA connector

Peripheral equipment



The MA1610A is a pulse modulator used in combination with the MG3633A Synthesized Signal Generator to generate high-speed pulse modulated signals. The MA1610A can switch RF signals with a carrier frequency ranging from 10 kHz to 2700 MHz ON and OFF using an input modulation signal (TTL level, 50 Ω terminated). Power is supplied from the MG3633A via its rear panel AUX connector.

Frequency range	10 kHz to 2700 MHz			
ON,OFF ratio	≥60 dB (<1000 MHz), ≥40 dB (≥1000 MHz)			
Insertion loss	≤2 dB (<1000 MHz), ≤3.5 dB (<1000 MHz)			
Rise time	≤15 ns			
Fall time	≤5 ns			
Minimum pulse width	20 ns			
Maximum repetition rate	10 MHz			
Maximum delay time	40 ns			
Video feed through	≤50 mVp-p			
Overshoot/ringing	≤20%			
RF input/output	50 Ω , N-type connector, maximum permissible input level: AC 200 mW, DC 3.5 V			
Operating temperature	0° to 50°C			
Dimensions and mass	131 (W) x 57 (H) x 43 (D) mm, ≤600 g			
Standard accessories	J0494: Coaxial cord, 0.3 m (1 pc) J0495: Power cord, 1.0 m (1 pc) W0508AE: MA1610A operation manual (1 copy)			

Ordering information

Please specify model/order number, name, and quantity when ordering.

Please specify model/order number, name, and quantity when ordering				
Model/Order No.	Name			
MG3633A	Main frame Synthesized Signal Generator			
J0025A J0127A F0013 F0012 W0504AE	Standard accessories Coaxial cord (S-5DWP · 5D-2W · S-5DWP), 1 m: 1 pc Coaxial cord (BNC-P · RG58A/U · BNC-P), 1 m: 1 pc Power cord, 2.5 m: 1 pc Fuse, 5 A (for 100 Vac mains): 2 pcs Fuse, 3.15 A (for 200 Vac mains): 2 pcs MG3633A operation manual: 1 copy			
MG3633A-01 MG3633A-02 MG3633A-03 MG3633A-04	Options Reference oscillator Reference oscillator Reference oscillator Reference oscillator Rear RF output: SMA connector (however, replaces front-panel RF connector)			
MA1610A	Peripheral Pulse Modulator (10 kHz to 2.7 GHz)			
MP614B MA1612A MP659A Z-164A MB24A	Optional accessories $50~\Omega \leftrightarrow 75~\Omega~\text{Impedance Transformer} \\ (50~\Omega \leftrightarrow 75~\Omega,~10~\text{MHz to 1.2 GHz}) \\ \text{Four-Port Junction Pad (5 MHz to 3 GHz)} \\ \text{Four-Port Junction Pad (40 to 1000 MHz)} \\ \text{T-pad (DC to 1000 MHz)} \\ \text{Portable Test Rack}$			